

SNP High Performances IR Microchip Series



KEY FEATURES

- Repetition rate up to 130 kHz
- Ultrashort pulses down to 600 ps
- Multi-kW peak power
- Excellent beam quality TEM00, M²<1.2
- Efficient, air-cooled
- Sealed package, extremely long life

For generating high peak power IR pulses of a few hundred picoseconds, microchip lasers are economical, compact, and reliable. Sub-nanosecond 1064nm pulses are indeed directly generated from the diode pumped passively Q-switched Nd:YAG microchip engine. Microchips are also easy to operate and service ; controllers can be used with every laser head model and swapped within minutes while conserving constant performances. The SNP series are designed for high average power, either from pulse energies of 20 µJ at 1064nm, or from repetition rates up to 130 kHz.

APPLICATIONS

- Material processing
 Cost effective marking solutions
 - Graphitization

- Instrumentation
 - Ranging
 - Differential absorption LIDAR
 - Super-continuum generation
 - -Distributed temperature sensing
 - Raman spectroscopy

- Biophotonics
 - Nanosurgery
 - Protein cross-linking

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TECHNICAL SPECIFICATIONS

								New!
	SNP-08E-100	SNP-18E-100	SNP-20F-100	SNP-50F-100	SNP-70F-100 SLM	SNP-130F- 100	SNP-200P- 100	SNP-300P- 100
Wavelength	1064nm	1064nm	1064nm	1064nm	1064nm	1064nm	1064nm	1064nm
Repetition Rate Constant Pulse width	>5kHz <1ns	>13kHz >3ns	>19kHz <1ns	>45kHz <0.7ns	>65kHz <0.6ns	>130kHz <1.4ns	>19 KHz <0.85 ns	>29 KHz <0.75 ns
range (FWHM) (1) Output power ⁽²⁾	>40mW >8µJ >8kW	>300mW >18µJ N/A	>140mW >7µJ >10kW	>190mW >4µJ >5.5kW	> 90mW >1µJ >2kW	>200mW >1.5µJ >1.1kW	>200mW >11µJ >13kW	>300mW >10µJ >13kW
Output energy Peak Power								
Short term (1min) power stability ⁽³⁾	<±1%	<±2%	<±1%	<±1%	<±1%	<±1%	<±1%	<±1%
Long term (6 hrs) power stability ⁽³⁾	<±3%	<±5%	<±3%	<±3%	<±3%	<±3%	<±3%	<±3%
Beam profile Full angle	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00	Gaussian TEM00
divergence Horizontal@1/ e ² Vertical@1/e ²		5.2±1 mrad ⁽⁶⁾ 5.1±1 mrad ⁽⁶⁾ <1.3	13±5mrad 13±5mrad <1.3	17±3mrad 17±3mrad <1.3	22±3mrad 22±3mrad <1.3	17±2.5mrad 17±2.5mrad <1.3	13±2mrad 13±2mrad <1.3	15±2mrad 15±3mrad <1.3
M ²⁽⁴⁾ Beam ellipticity ⁽⁵⁾	<1.3	<1.3	<1.3	<1.3	<1.3	<1.3	<1.2	<1.2
Polarization	Linear PER>20dB	Elliptical ⁽⁷⁾	Linear PER>20dB	Linear PER>20dB	Linear PER>20dB	Linear PER>20dB	Linear PER>20dB	Linear PER>20dB
Package dimensions	115x29x36m m	145x42x36m m	145x42x36m m	145x42x36m m	145x42x36m m	145x42x36m m	145x42x36m m	145x42x36m m
Package weight	250g	300g	300g	300g	300g	300g	300g	300g
Options (table p3)	None	None	F,M,S	F,M,S	F,M,S	F,M,S	F,M,S	F,M,S

NOTES

(1) Measured with 1Ghz photodiode and 1GHz/10GS/s oscilloscope.

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 Measurement performed with an OPHIR thermal power sensor (OPHIR 3A-FS-SH)
 For temperature variation < ± 3°C and < 3°C/hour, stability is measured with calorimeter - detector band [DC, 2Hz]
 Mean average value M = √(XY), X and Y being respectively the major and minor axis of the ellipse
 Beam ellipticity is calculated as the ratio of the main axis far field divergence
 Collimated beam available as an option
 Linear polarization available as an option



COMPLEMENTARY INFORMATION & OPTIONS

Environment Parameters				
Operating Temperature Range	0-50°C			
Maximum Laser Head Baseplate Temperature	<50°C			
Maximum Power Consumption	<40W			
Laser Head Thermal Dissipation	<15W			
Storage Temperature	0-50°C			
Shock of 11ms according to IEC 68-2-27, non operating	25g			
Vibration 5Hz to 500Hz sinusoïdal according to IEC 68-2-6	2g			

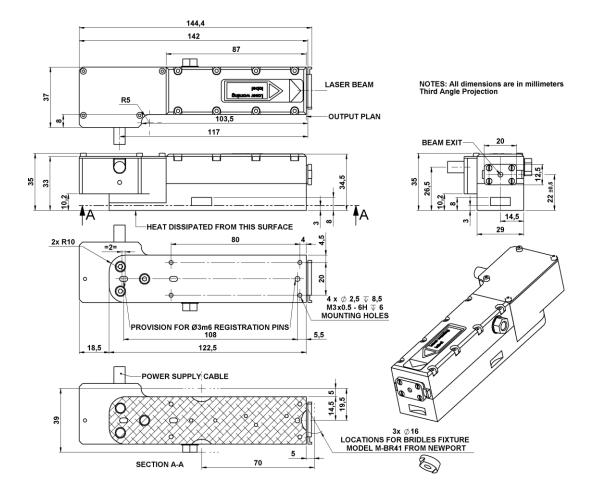
Certification					
Laser classification according to IEC 60825-1:2007	3B				
CDRH	Yes, if used with a -DR1 controller				
ROHs	Yes				

Options	
Multimode fibering (M)	Contact factory for availability
Single mode fibering (F)	Contact factory for availability
Synchronization output (S)	Contact factory for availability

Available Controller Types							
Model for the SNP-300P-100	Model for the other SNP lasers	Туре	Input Power	CDRH			
MLC-05A-DR1	MLC-03A-DR1	Desktop	100-240 V AC	Yes			
MLC-05A-MR1	MLC-03A-MR1	Module	12 V DC	No			
MLC-05A-BR1	MLC-03A-BR1	Board	12 V DC	No			



CDRH LASER HEAD MECHANICAL DRAWINGS: SNP-18E-100, SNP-20F-100, SNP-50F-100, SNP-130F-100, SNP-200P-100, SNP-300P-100

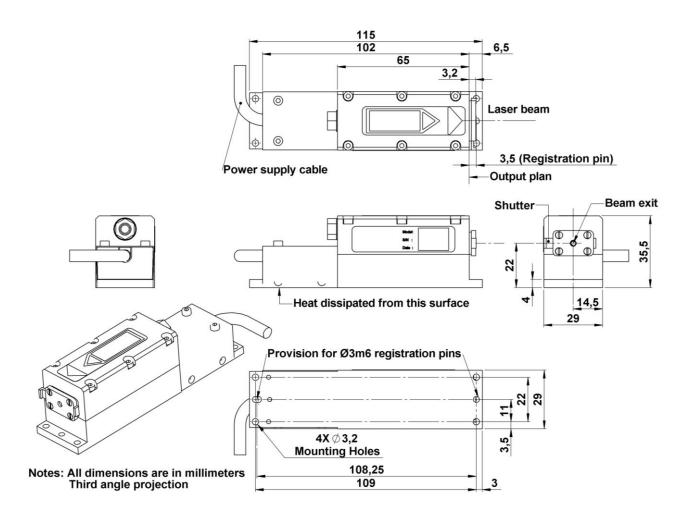


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CDRH LASER HEAD MECHANICAL DRAWINGS: SNP-08E-100



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